

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
60V	50mΩ @ V _{GS} = 10V	24A
000	65mΩ @ V _{GS} = 4.5V	21A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Engine management systems
- Body control electronics
- **DC-DC** converters

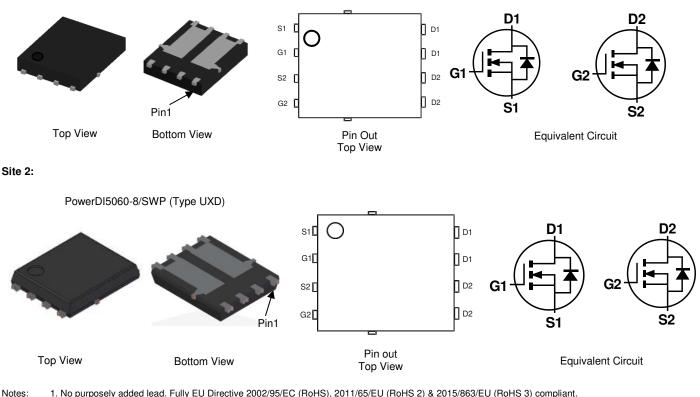
Features and Benefits

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON)-Minimizes Power Losses
- Low Q_G—Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMNH6042SPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Site 1:

PowerDI5060-8 (Type C)

Site 2:

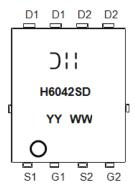


Ordering Information (Note 4)

Part Number	Baakaga	Packing		
Part Nulliber	Package	Qty.	Carrier	
DMNH6042SPDQ-13	PowerDI5060-8 (Type C)	2500	Tape & Reel	
DMNH6042SPDQ-13	PowerDI5060-8/SWP (Type UXD)	2500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking H6042SD = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	60	V		
Gate-Source Voltage	VGSS	±20	V		
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	$T_{A} = +25^{\circ}C$ $T_{A} = +70^{\circ}C$	ID	5.7 4.6	A
Continuous Drain Current (Note 7) V_{GS} = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	24 17	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	IDM	32	A		
Maximum Continuous Body Diode Forward Current	ls	24	А		
Avalanche Current (Note 8) L = 10mH	las	3.5	А		
Avalanche Energy (Note 8) L = 10mH			Eas	65	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.2	W
Thermal Desistance lunction to Ambient (Nets 5)		P	105	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	Reja	54	C/W
Total Power Dissipation (Note 6)		PD	2.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Davi	51	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	Reja	26	
Thermal Resistance, Junction to Case (Note 7)		Rejc	3.5	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.

Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.



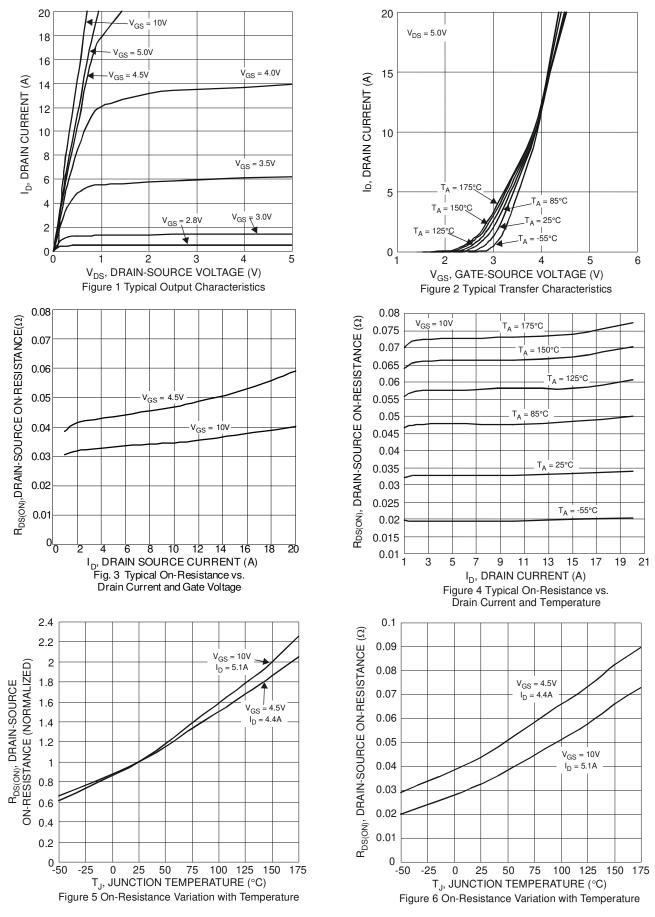
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			-			T LO IN	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)			1	1		1	
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_		1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Bracon	—	34	50	mΩ	$V_{GS} = 10V, I_D = 5.1A$	
	RDS(ON)	—	45	65	11152	$V_{GS}=4.5V,\ I_D=4.4A$	
Diode Forward Voltage	VSD	_	0.8	1.2	V	VGS = 0V, IS = 2.6A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	CISS	—	584	_	pF		
Output Capacitance	Coss	—	83	_	pF	VDS = 25V, VGS = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	24	_	pF		
Gate Resistance	Rg	_	3.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q _G	_	4.2	_	nC		
Total Gate Charge (V _{GS} = 10V)	QG	_	8.8	_	nC	VDS = 44V. ID = 5.2A	
Gate-Source Charge	Qgs	_	1.8	_	nC	VDS = 44V, ID = 5.2A	
Gate-Drain Charge	Qgd	_	1.8	_	nC		
Turn-On Delay Time	td(ON)	_	3.4	_	ns		
Turn-On Rise Time	tR	_	1.9	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	tD(OFF)	_	10.1		ns	$R_G = 6\Omega, I_D = 1A$	
Turn-Off Fall Time	tF	_	4.5	_	ns		
Body Diode Reverse Recovery Time	trr		12.9		ns	IF = 2.6A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	QRR		5.4		nC	IF = 2.6A, di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

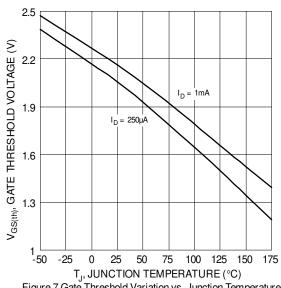


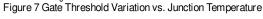
DMNH6042SPDQ

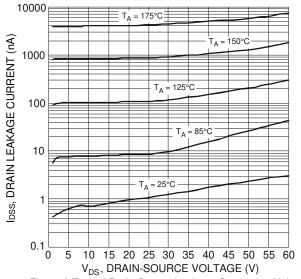


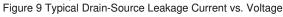
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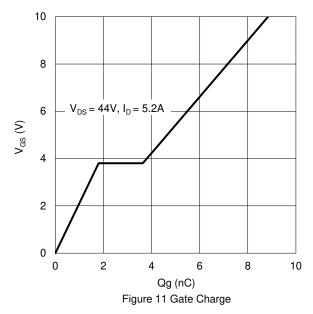


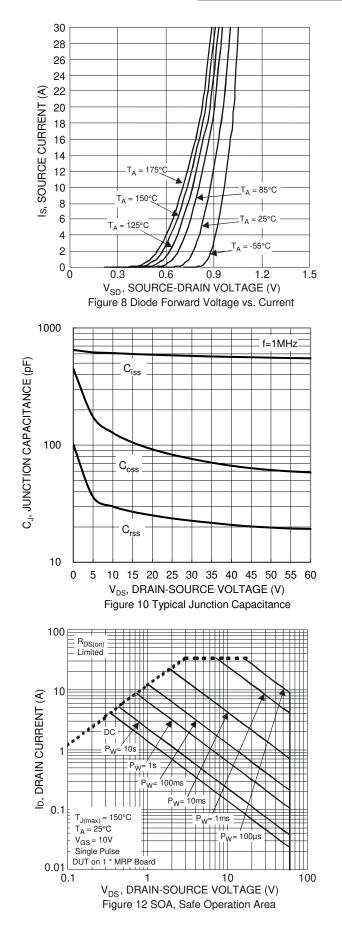






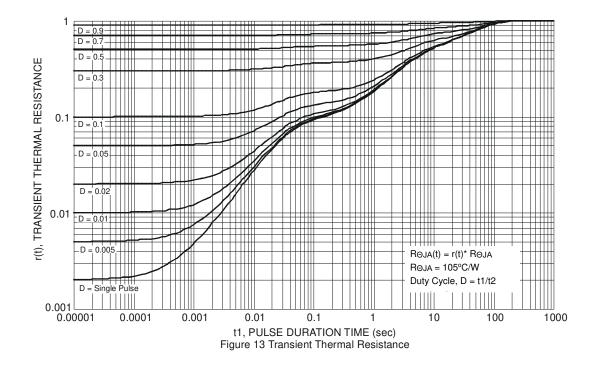






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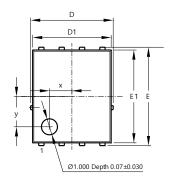


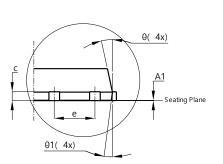


Package Outline Dimensions

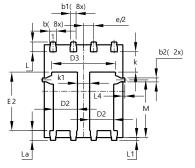
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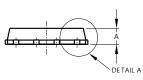
PowerDI5060-8 (Type C)





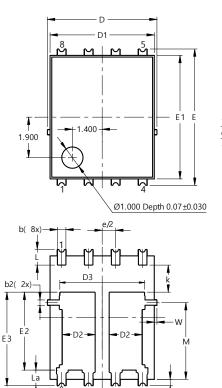
DETAIL A





Pow	PowerDI5060-8 (Type C)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
С	0.23	0.33	0.277		
D	5	.15 BS0	0		
D1	4.85	4.95	4.90		
D2	1.40	1.60	1.50		
D3	-	-	3.98		
Е	6	.15 BS0	2		
E1	5.75	5.85	5.80		
E2	3.56	3.76	3.66		
е	1	.27BSC			
k	-	-	1.27		
k1	0.56	-	-		
L	0.51	0.71	0.61		
La	0.51	0.71	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

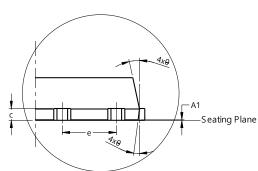
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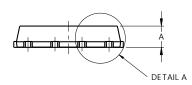
-b4(8x)

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PowerDI5060-8/SWP (Type UXD)



DETAIL A



PowerDI5060-8/SWP (Type UXD)				
Dim	Min			
Α	0.90	1.10	1.00	
A1	0.00	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	().25REF	-	
С	0.230	0.330	0.277	
D	5	6.15 BS0	2	
D1	4.70	5.10	4.90	
D2	1.46	1.66	1.55	
D3			3.98	
E	6	6.40 BSC		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е		.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
М	3.205	4.005	3.605	
W	0.025	0.225	0.125	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

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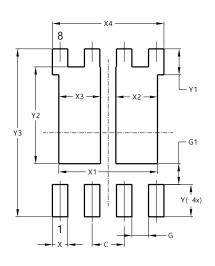


Suggested Pad Layout

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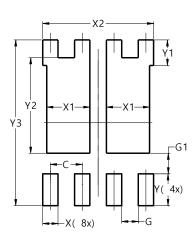
PowerDI5060-8 (Type C)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	3.910
X2	1.650
X3	1.650
X4	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610

Site 2:

PowerDI5060-8/SWP (Type UXD)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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